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# Instability of the topological surface state in $\text{Bi}_2\text{Se}_3$ upon deposition of gold

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Momentum resolved photoemission spectroscopy indicates the instability of the Dirac surface state upon deposition of gold on the (0001) surface of the topological insulator  $\text{Bi}_2\text{Se}_3$ . Based on the structure model derived from extended x-ray absorption fine structure experiments showing that gold atoms substitute bismuth atoms, first principles calculations provide evidence that a gap appears due to hybridization of the surface state with gold  $d$ -states near the Fermi level. Our findings provide new insights into the mechanisms affecting the stability of the surface state.

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Topological protection of the Dirac electrons at the three-dimensional topological insulator (TI) surface caused enormous interest in these materials as potential candidates for spintronics [1, 2]. This remarkable property guarantees that the Dirac electrons of a TI surface do not experience the backscattering whatever the surface quality is. The only crucial condition to be met to secure that behavior is the absence of the time-reversal symmetry breaking perturbations, for instance, an out-of-plane ferromagnetism. Therefore, since the very discovery of the three-dimensional TIs, considerable experimental effort has been devoted to the confirmation of the topological protection. The most striking evidences of the property include the absence of the elastic backscattering on the disordered or defected surfaces [3–6], existence of the well-defined Dirac states at the thallium-based 3D TI's surfaces exhibiting complex morphology [7, 8], and the tolerance of the topological states to the in-plane [9, 10] or, possibly, non-collinear [11] magnetic moments.

The property of the topological protection is intimately related to the topological surface state (TSS) integrity. In particular, the time-reversal symmetry leads to a crossing of the surface states at the 2D Brillouin zone center. To gap out the Dirac point (DP) an effective mass term has to be taken into account, e.g. by applying a magnetic field in  $z$  direction [12–17]. Otherwise, both experimentally and theoretically, the DP and TSS were found to be robust upon deposition of various adsorbates [18–21] and overlayers [22–24]. However recently, it has

been found that the TSS can be destroyed by strain in the vicinity of grain boundaries on the surface of epitaxial  $\text{Bi}_2\text{Se}_3$ (0001) thin films [25] and in  $\text{Pb}_{1-x}\text{Sn}_x\text{Te}$  [26]. More recently, for the bulk alloy  $(\text{Bi}_{1-x}\text{Mn}_x)_2\text{Se}_3$ , the influence of Mn-induced ferromagnetic order was excluded from being responsible for the formation of the 100 meV band gap [27]. It was argued that the system remains topologically non-trivial while in-gap resonance states of  $d$ -symmetry are involved in the gap opening [27]. This view is supported by theoretical studies suggesting the formation of impurity (vacancy) resonance states near the DP [28–30], located in the bulk or in the near surface region. These resonance states hybridize with the TSS, which is destroyed and the DP is energetically split. As pointed out in Ref. 30 the topological protection of the TSS is only valid for two-dimensional backscattering but there is no protection against scattering by bulk states, which may originate from non-magnetic and magnetic impurities.

Since the experiment in Ref. [27] only dealt with bulk alloys it remains an open question whether the disruption of the TSS also occurs in the case of a surface alloy prepared by in situ deposition of (sub-) monolayer amounts of an adsorbate on a TI surface. [As was already proven before, a topological surface state is generated by the electronic structure of the bulk and is mainly located in the two first quintuple layers \(QL\) \[1\]. Therefore, one cannot exclude that the TSS in the experiment in Ref. \[27\] is destroyed due to substantial changes in](#)

structural or electronic properties of the whole sample. In addition, the magnetic nature of the band gap opening was not fully ruled out: Mn can form clusters with nonzero magnetization. Also, each Mn atom possesses a magnetic moment, which can strongly interact with the free electron gas. Such an electron-magnon interaction can also induce the band gap opening [31].

In order to elucidate the mechanism by which the TSS is modified by doping with an impurity we have carried out a combined experimental and theoretical study to investigate the effect of a prototype *non-magnetic* surface alloy like gold on the (0001) surface of a  $\text{Bi}_2\text{Se}_3$  single crystal, in the following written as  $(\text{Bi}_{1-x}\text{Au}_x)_2\text{Se}_3$ . The structure analysis by extended x-ray absorption fine structure (EXAFS) experiments provides evidence that gold atoms deposited at  $T=160$  K substrate temperature substitute bismuth atoms within the near-surface regime. Simultaneously, photoemission experiments carried out at 0.3, 0.5 and 1 ML coverage indicate the opening of a gap at the DP of the TSS even at a coverage of 0.3 ML equivalent to  $x=0.15$ . Here, and in the following we refer to 1 ML as  $6.74 \times 10^{14}$  atoms/cm<sup>2</sup>, i.e., one ad-atom per surface atom. *Ab-initio* calculations based on the model structure show that the modification of the TSS already begins between  $x=0.0125$  and  $x=0.0375$ . They perfectly reproduce the experimental spectral function recorded by photoemission. We conclude that impurity states of *d*-symmetry located within the topmost QL are responsible for the gap opening. Our results provide an experimental and theoretical proof that even nonmagnetic surface impurities create resonance states near the DP, involving scattering by bulk like states [28–30].

EXAFS measurements were carried out at the Sector 20 insertion device beamline at the Advanced Photon Source (APS), Argonne National Laboratory (USA) using the MBE1 end station equipped with standard surface analytical tools [32]. Two samples were investigated corresponding to a film coverage of 0.3 and 0.6 monolayers (ML) of gold as estimated by AES spectra in combination with reflection high energy electron diffraction oscillations. After gold deposition on the pristine  $\text{Bi}_2\text{Se}_3$ (0001) surface EXAFS data were collected above the  $\text{Au-L}_{III}$  absorption edge ( $E_0=11919$  eV) in the fluorescent yield (FY) mode using a 4-element Vortex Si drift detector. From AES experiments it was concluded that in-diffusion of gold into the  $\text{Bi}_2\text{Se}_3$  bulk sets in above 250 K. For this reason gold deposition and EXAFS measurements were carried out at  $T=160$  K. Monochromatic x-rays from a Si(111) double-crystal monochromator, with the 7 GeV APS ring operating in top-up mode, were incident on the substrate at approximately 2/3 of the critical angle ( $\alpha_c \approx 0.4^\circ$ ) for total reflection to avoid errors due to anomalous dispersion effects [33]. The in-plane and out-of-plane gold atomic environment was investigated exploiting the polarization dependence of the linearly polarized x-ray beam with the electric field vec-

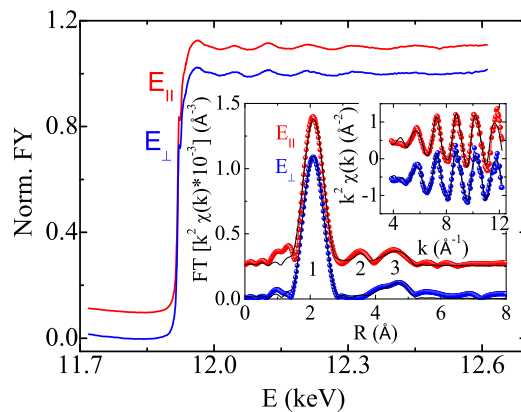


FIG. 1. (Color online) Normalized fluorescence yield collected for about 0.6 ML of gold deposited on  $\text{Bi}_2\text{Se}_3$ (0001) with the electric field vector parallel ( $E_{\parallel}$ ) and perpendicular ( $E_{\perp}$ ) to the sample surface. Curves are shifted for clarity. The inset shows the  $k^2$ -weighted interference function  $[\chi(k)]$  and the magnitude of the Fourier-Transforms. The absence of any polarization dependence of peak 1 indicates a nearly isotropic environment compatible with the substitutional site (see Fig. 2). The reduction of peak 2 in the magnitude of the Fourier Transform of  $E_{\perp}$  is predicted for the substitutional site.

tor aligned either perpendicular ( $E_{\perp}$ ) or parallel ( $E_{\parallel}$ ) to the plane of the substrate.

Fig. 1 shows for the 0.6 ML sample the fluorescent yield (FY) versus photon energy for both geometries which is proportional to the linear absorption coefficient. The inspection of the figure reveals that both curves are nearly identical. The detailed analysis was carried out by background subtraction and calculation of the Fourier-Transform (FT) of the  $k^2$ -weighted interference function  $[\chi(k)]$ , which are shown in the inset.

The FT magnitude shows three peaks labelled by 1, 2 and 3 for  $E_{\parallel}$ , but only 1 and 3 for  $E_{\perp}$ . Peak 1 corresponds to the first selenium shell, while peaks 2 and 3 are related to bismuth shells. For the present discussion we focus on the first shell, which was fitted in R-space using theoretical scattering amplitudes and phases. The fit results are listed in Table . In detail, we find that the first peak corresponds to in total six selenium atoms of which three are located at a distance of 2.45 Å and another three at a distance of 2.65 Å ( $E_{\parallel}$ ). For  $E_{\perp}$  geometry the distances can be viewed as identical. The structure parameters are compatible with a model, in which gold atoms substitute bismuth atoms.

Comparison of the experimental first shell distances with those in the un-relaxed bulk ( $R=2.87$  Å and  $R=3.07$  Å) indicates substantial local relaxations of the surrounding selenium atoms upon bismuth substitution. This situation closely resembles that of iron deposition on  $\text{Bi}_2\text{Se}_3$ (0001) [11], where very similar structure parameters have been derived.

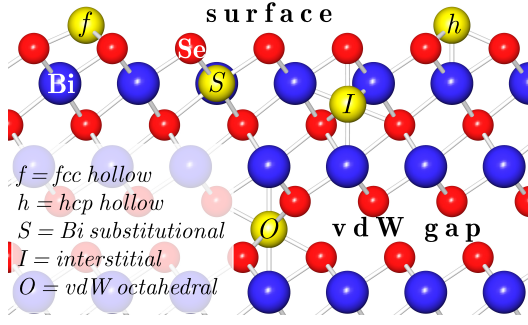


FIG. 2. (Color online) Schematic view of adsorption sites for gold on  $\text{Bi}_2\text{Se}_3(0001)$ . Bismuth and selenium atoms are shown as large blue and small red spheres, respectively. Possible gold positions are indicated by yellow spheres and labelled by "f", "h", "S", "I", and "O" for the fcc, hcp, substitutional, interstitial and octahedral van der Waals gap sites, respectively.

TABLE I. Table of structural parameters for 0.6 ML Au on  $\text{Bi}_2\text{Se}_3$ . The meaning of the parameters is as follows:  $R$ := refined neighbor distance,  $R_b$ := distance in unrelaxed bulk structure,  $N^*$ := effective polarization dependent coordination number for  $L_{III}$  edge [35],  $\sigma^2$ := mean squared relative displacement amplitude,  $\Delta E_0$ : shift of absorption edge,  $R_u$ := Residual in percent [36]. The amplitude reduction factor ( $S_0^2$ ) was kept constant at  $S_0^2=0.80$  in all cases. Parameters labelled by an asterisk (\*) are kept fixed. Uncertainties are given in brackets.

Pol.	Sh	$R_b(\text{\AA})$	N	$R(\text{\AA})$	$N^*$	$\sigma^2(\text{\AA}^2)$	$\Delta E_0(\text{eV})$	$R_u$
E	Se1	2.87	3	2.45 (3)	3.04(*)	0.004	2.6	4.9
	Se2	3.07	3	2.65 (4)	2.92(*)	0.014	2.6	
E⊥	Se1	2.87	3	2.44 (3)	2.92(*)	0.004	3.3	2.3
	Se2	3.07	3	2.66 (4)	3.16(*)	0.021	3.3	

The structure model is discussed on the basis of Fig. 2, where the near surface structure of  $\text{Bi}_2\text{Se}_3$  including the first QL is schematically shown. Large (blue) and small (red) spheres represent bismuth and selenium atoms, respectively. The  $\text{Bi}_2\text{Se}_3$  crystal structure is characterized by an ABCBA stack of van-der-Waals (vdW) bonded QLs each being composed of a Se-Bi-Se-Bi-Se sequence of layers [34]. Possible adsorption positions for gold are indicated and are labelled as "fcc" (f), "hcp" (h), "substitutional" (S), "interstitial" (I) and "octahedral gap" (O). The absence of any polarization dependence of the peak 1 as well as its relation to a distance in the 2.5 to 2.7 Å range leads to a model where gold atoms are substituting bismuth atoms. Other adsorption sites such as the "fcc" or "hcp" sites at the surface or interstitial sites are not compatible with both the isotropy of the first peak and its relation to a Au-Se bond length.

Spin-resolved photoemission experiments were carried out using a momentum microscope (MM) [37] equipped

with a 2D imaging spin filter based on low-energy electron diffraction at 1 ML Au/Ir(001) [38]. Sample preparation which closely followed the procedure employed for the EXAFS experiments and experimental details are reported in the Supplementary Materials. The photoemission spectra collected by the MM for pristine and gold-covered  $\text{Bi}_2\text{Se}_3(0001)$  are displayed along the  $\bar{M}-\bar{\Gamma}-\bar{M}'$  direction in Fig. 3(a-e), respectively. In the case of the pristine  $\text{Bi}_2\text{Se}_3$  sample [Fig. 3(a)], the DP is located approximately 350 meV below  $E_F$  resulting from  $n$  doping by selenium vacancies. After deposition of 1 ML of gold [Fig. 3(b)], the TSS is strongly broadened by the structural disorder introduced by the randomly distributed gold atoms on Bi sites.

More details are derived by spin-resolved spectra collected for 0.3, 0.5 and 1 ML as shown in Figs. 3(b-e). Here, the characteristic spin-momentum locking of the surface state is observed. Gold deposition induces an upwards shift (p-doping) and -more importantly- an opening of the gap which amounts to about 100 meV. The surface state dispersion is not observed to continue into the energy range below the black dashed lines where the two spin-polarized branches meet at  $k_x=0$  [see Fig. 3(d,e)]. The experimental findings are well reproduced by ab-initio calculations as discussed in the following.

First-principles calculations of Au/ $\text{Bi}_2\text{Se}_3(0001)$  model gold induced modifications of the TSS. We used a self-consistent full relativistic Green function method especially designed for semi-infinite materials such as surfaces and interfaces [39, 40]. Alloying the bismuth layers with gold was simulated within a coherent potential approximation as implemented within the multiple scattering theory [41, 42]. The structural information was adopted from the EXAFS experiments (see Table ).

In order to trace the evolution of the TSS upon gold concentration the  $k$ -resolved spectral density was calculated in  $(\text{Bi}_{1-x}\text{Au}_x)_2\text{Se}_3$  on the  $\text{Bi}_2\text{Se}_3(0001)$  surface for  $\bar{K}-\bar{\Gamma}-\bar{M}$  direction in SBZ at concentrations  $x = \{0.0125, 0.0375, 0.0625, 0.125\}$  (see (Fig. 4(a-d), respectively). In all these cases Au is assumed to be homogeneously distributed over the Bi sites within the first QL. The results are shown in Fig. 4, where low, medium and high spectral density is represented by blue, white and red color coding, respectively. At  $x = 0.0125$  [see Fig. 4(a)], the spectral density is similar to that of the pristine  $\text{Bi}_2\text{Se}_3(0001)$  surface (not shown), but some broadening is seen in the vicinity of  $E_F$ , which is attributed to a gold resonance state.

The most important result is that gold substitution induces the formation of a gap of  $\Delta E=200$  meV, in a good agreement with photoemission spectra. Within the gap regime the spectral density is considerably weakened due to the presence of a resonance state and because of band broadening induced by structural disorder. Furthermore, gold acts as a p-dopant shifting the bands up in energy. Comparison of the calculated band structure of the pris-

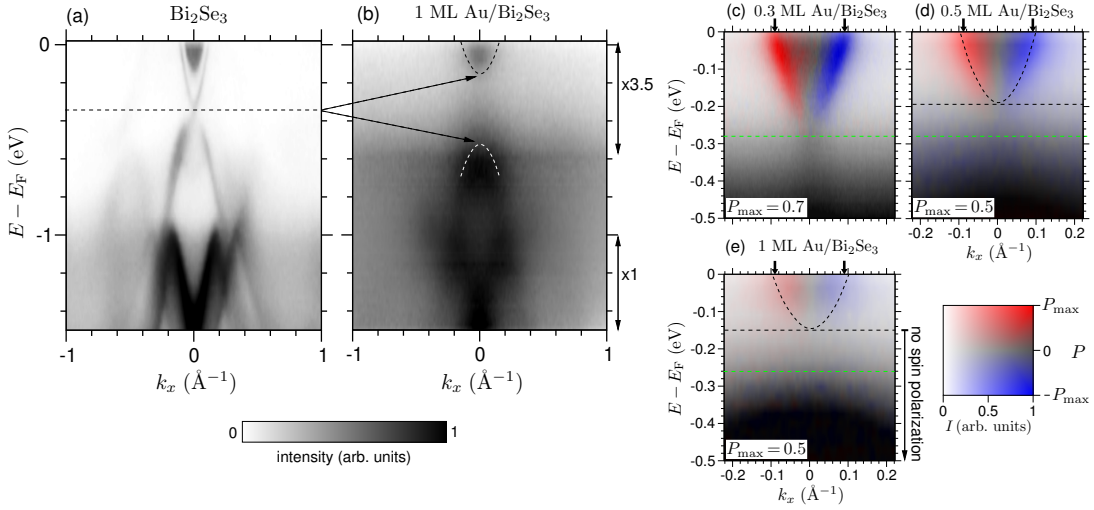


FIG. 3. (a-b): Spin integrated photoemission spectra of pristine and gold-covered  $\text{Bi}_2\text{Se}_3$  using unpolarized He-I radiation ( $h\nu = 21.2$  eV). (c-e): Spin-resolved spectra using s-polarized laser light ( $h\nu = 6.0$  eV) collected for 0.3, 0.5 and 1.0 ML of gold. Dashed lines indicate the opening of a gap in the surface state. Further details are provided in the Supplementary Materials.

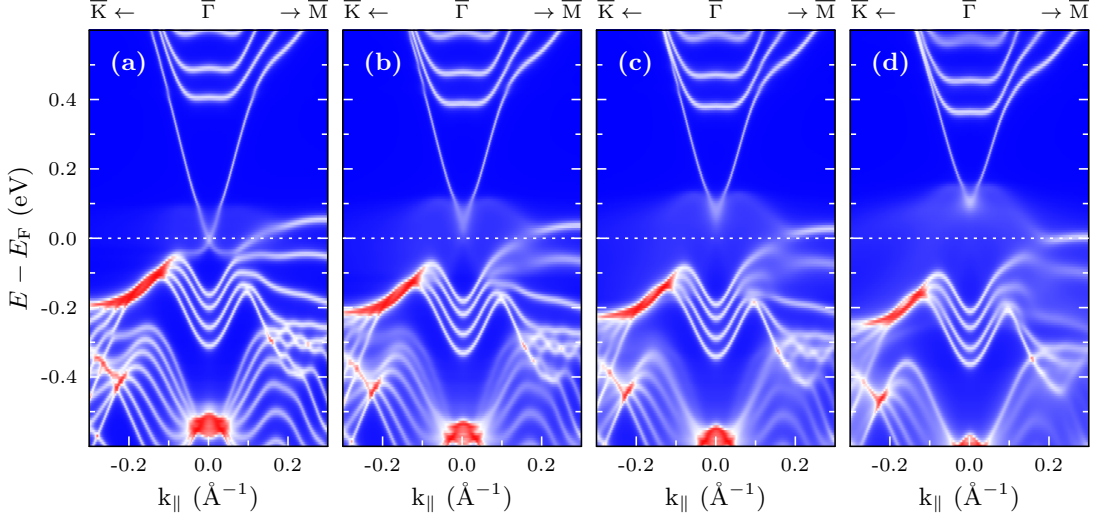


FIG. 4. (Color online) Evolution of the TSS in  $(\text{Bi}_{1-x}\text{Au}_x)_2\text{Se}_3/\text{Bi}_2\text{Se}_3(0001)$ : Calculated spectral density for  $x = 0.0125$  (a),  $x = 0.0375$  (b),  $x = 0.0625$  (c), and  $x = 0.1250$  (d), respectively.

tine surface (not shown here) and the alloyed sample indicate an upward shift of the bands by approximately 330 meV (at  $x = 0.5$ ).

Our study provides new insight into the non-magnetic impurity mediated modification of the TSS. Gold atoms deposited in the sub- to one monolayer range on  $\text{Bi}_2\text{Se}_3(0001)$  occupy substitutional bismuth sites as evidenced by EXAFS measurements. This goes in parallel with the dramatic weakening of the spectral density of the TSS, thus opening a gap as observed by photoemission. In accordance with first-principles calculations, gold in bismuth substitutional site within the first QL creates a d-type resonant state near the  $E_F$ , which strongly hybridizes with the bands of the TI and sub-

stantially modifies its surface electronic structure. The surface alloy involving only the topmost QL is sufficient for the gap opening, which we attribute to the fact that the resonance state near  $E_F$  is of d-symmetry. According to the model of Black-Schaffer and Balatsky [28–30] a bulk-surface interaction is a prerequisite for the opening of the gap, since the TSS is not protected by scattering processes involving bulk three-dimensional states.

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